

IN THE CLAIMS

Please make the following amendments to the claims:

- 1-12. (Canceled)
13. (Currently Amended) The power initialization circuit as recited in claim ~~12~~18, further comprising a buffer unit for outputting the power-up signal by buffering an output signal of the reset prevention unit.
14. (Previously Presented) The power initialization circuit as recited in claim 13, wherein the buffer unit includes an inverter chain receiving the output signal of the reset prevention unit.
15. (Currently Amended) The power initialization circuit as recited in claim ~~12~~18, wherein the reset prevention unit further includes an inverter connected to the first pull-up means and the first pull-down means.
16. (Currently Amended) The power initialization circuit as recited in claim ~~12~~18, wherein each of the first and the second pull-up devices is a PMOS transistor, and the pull-down means is an NMOS transistor.
17. (Currently Amended) The power initialization circuit as recited in claim ~~12~~18, wherein the power supply voltage level follower unit is provided between the power supply voltage and a ground voltage, and includes a first and a second load element configured as a voltage divider.

18. (Currently Amended) ~~The power initialization circuit as recited in claim 12, A~~
power initialization circuit for a semiconductor memory device, comprising:

a power supply voltage level follower unit to provide a bias voltage which varies linearly with a power supply voltage;

a power supply voltage detection unit to detect when a level of the power supply voltage reaches a predetermined level to thereby generate a detection signal; and

a reset prevention unit to generate a power-up signal to thereby prevent a logic level of the power-up signal from transitioning during a power drop of the power supply voltage having a duration less than or equal to a predetermined period,

wherein the reset prevention unit includes:

a first pull-up means and a first pull-down means controlled by the detection signal;

a delay unit for delaying the detection signal by a predetermined time; and

a second pull-up means connected between the first pull-up means and a power supply voltage, and controlled by an output signal of the delay unit,

wherein the power supply voltage detection unit includes:

a load element connected between the power supply voltage and a first node;

an NMOS transistor which is connected between a ground voltage and the first node and whose gate receives the bias voltage; and

an inverter, which is connected to the first node, for outputting the detection signal.

19. (Previously Presented) The power initialization circuit as recited in claim 18, wherein the load element is a PMOS transistor which is connected between the power supply voltage and the first node and whose gate is connected to the ground voltage.